

# DS2007SF RECTIFIER DIODE

#### APPLICATIONS

- Rectification.
- Freewheel Diode.
- DC Motor Control.
- Power Supplies.
- Welding.
- Battery Chargers.

#### **FEATURES**

- Double Side Cooling.
- High Surge Capability.

#### **VOLTAGE RATINGS**

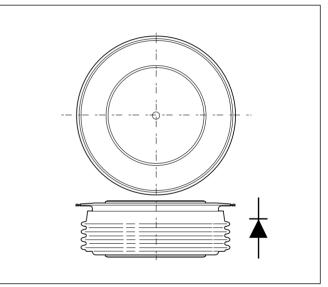
Type Number	Repetitive Peak Reverse Voltage V <sub>RRM</sub> V	Conditions
DS2007SF40	4000	$V_{RSM} = V_{RRM} + 100V$
DS2007SF39	3900	
DS2007SF38	3800	
DS2007SF37	3700	
DS2007SF36	3600	
DS2007SF35	3500	

Lower voltage grades available.

### **CURRENT RATINGS**

Symbol	Parameter	Conditions	Max.	Units			
Double Side Cooled							
I <sub>F(AV)</sub>	Mean forward current	Half wave resistive load, $T_{case} = 100^{\circ}C$	1225	А			
I <sub>F(RMS)</sub>	RMS value	$T_{case} = 100^{\circ}C$	1923	А			
I <sub>F</sub>	Continuous (direct) forward current	T <sub>case</sub> = 100°C	1720	А			
Single Side	e Cooled (Anode side)		·				
I <sub>F(AV)</sub>	Mean forward current	Half wave resistive load, $T_{case} = 100^{\circ}C$	820	А			
I <sub>F(RMS)</sub>	RMS value	$T_{case} = 100^{\circ}C$	1287	A			
I <sub>F</sub>	Continuous (direct) forward current	T <sub>case</sub> = 100°C	1050	A			

<b>KEY PARAMETERS</b>				
V <sub>RRM</sub>	4000V			
	1225A			
I <sub>FSM</sub>	25000A			



Outline type code: F. Turn to page 7 for further information.

# DS2007SF

# SURGE RATINGS

Symbol	Parameter	Conditions	Max.	Units
I <sub>FSM</sub>	Surge (non-repetitive) forward current	10ms half sine; $T_{case} = 150^{\circ}C$	20.0	kA
l <sup>2</sup> t	I <sup>2</sup> t for fusing	V <sub>R</sub> = 50% V <sub>RRM</sub> - 1/4 sine	2.0 x 10 <sup>6</sup>	A <sup>2</sup> s
I <sub>FSM</sub>	Surge (non-repetitive) forward current	10ms half sine; T <sub>case</sub> = 150°C	25.0	kA
l²t	I <sup>2</sup> t for fusing	V <sub>R</sub> = 0	3.125 x 10 <sup>6</sup>	A²s

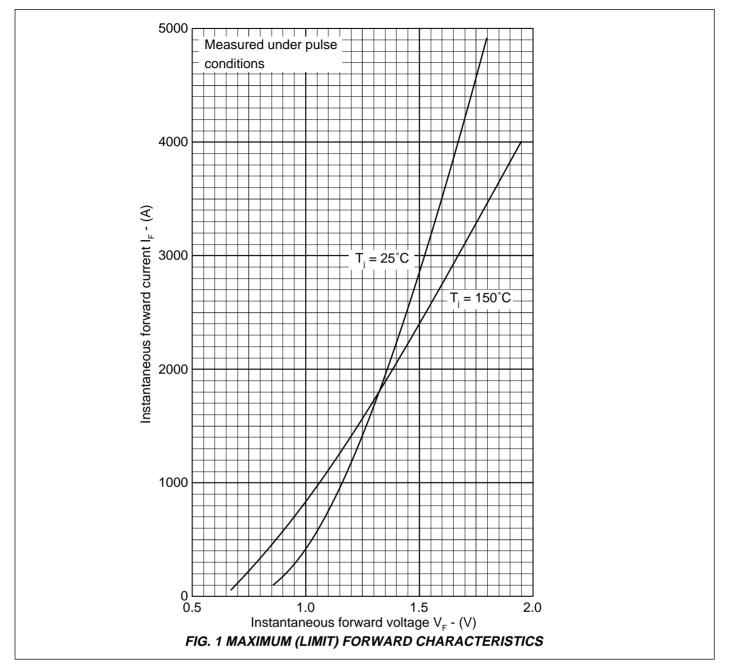
# THERMAL AND MECHANICAL DATA

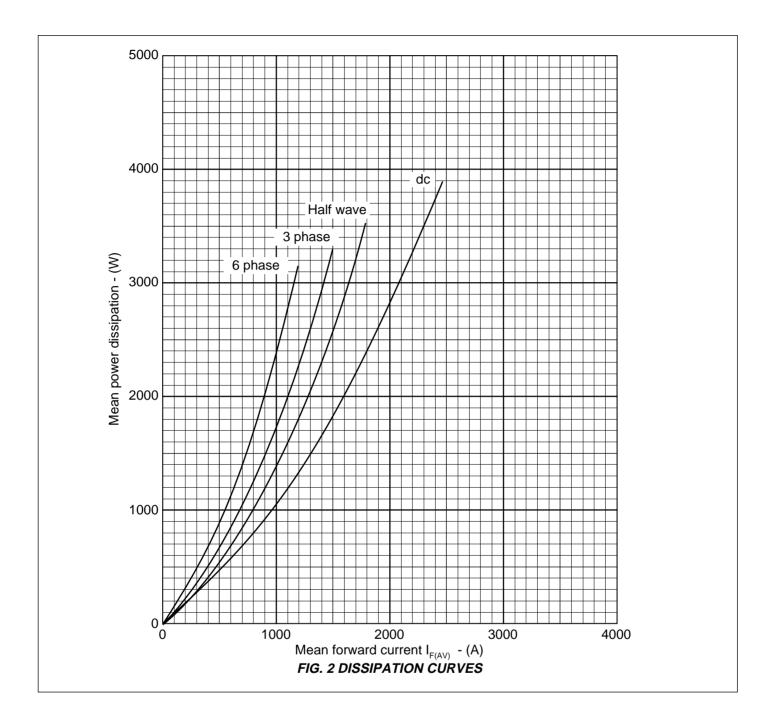
Symbol	Parameter	Conditions		Min.	Max.	Units
R <sub>th(j-c)</sub>	Thermal resistance - junction to case	Double side cooled	dc	-	0.022	°C/W
		Single side cooled	Anode dc	-	0.038	°C/W
			Cathode dc	- 0.004	- 0.052 °C/W	
P	Thermal resistance - case to heatsink	Clamping force 19.5kN with mounting compound	Double side	-	0.004	°C/W
R <sub>th(c-h)</sub>			Single side	-	0.008	°C/W
т	T <sub>vj</sub> Virtual junction temperature	Forward (conducting)		-	160	°C
l vj		Reverse (blocking)		-	150	°C
T <sub>stg</sub>	Storage temperature range			-55	175	°C
-	Clamping force			18.0	22.0	kN

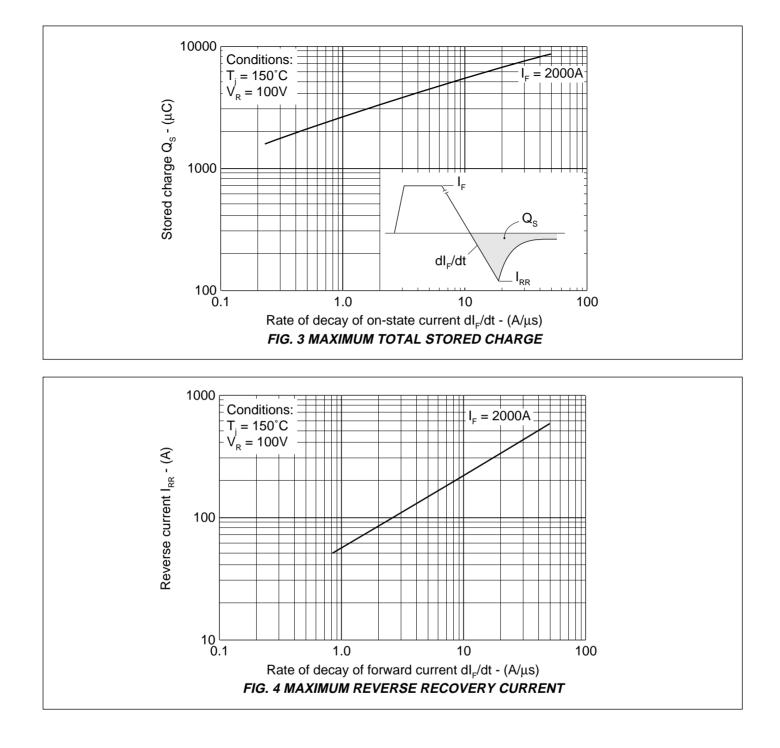
## CHARACTERISTICS

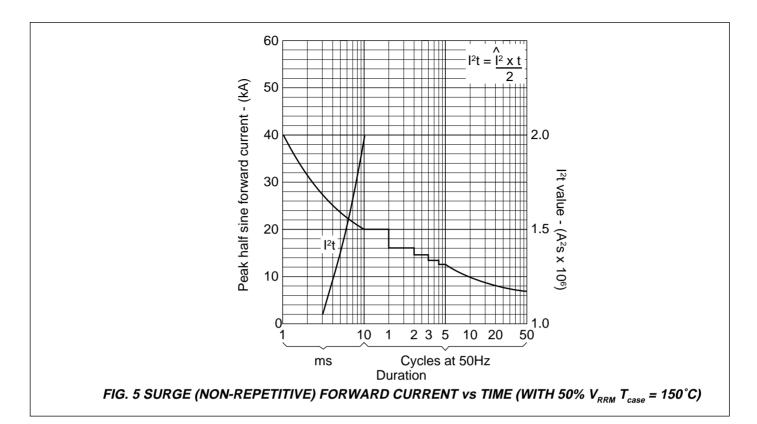
Symbol	Parameter	Conditions	Min.	Max.	Units
V <sub>FM</sub>	Forward voltage	At 3400A peak, T <sub>case</sub> = 25°C	-	1.6	V
I <sub>RRM</sub>	Peak reverse current	At $V_{\text{RRM}}$ , $T_{\text{case}} = 150^{\circ}\text{C}$	-	75	mA
Q <sub>s</sub>	Total stored charge	$I_{F} = 2000A, dI_{RR}/dt = 3A/\mu s,$	-	3500	μC
I <sub>RR</sub>	Peak recovery current	$T_{case} = 150^{\circ}C, V_{R} = 100V$	-	110	A
V <sub>TO</sub>	Threshold voltage	At $T_{vj} = 150^{\circ}C$	-	0.82	V
r <sub>T</sub>	Slope resistance	At T <sub>vj</sub> = 150°C	-	0.29	mΩ

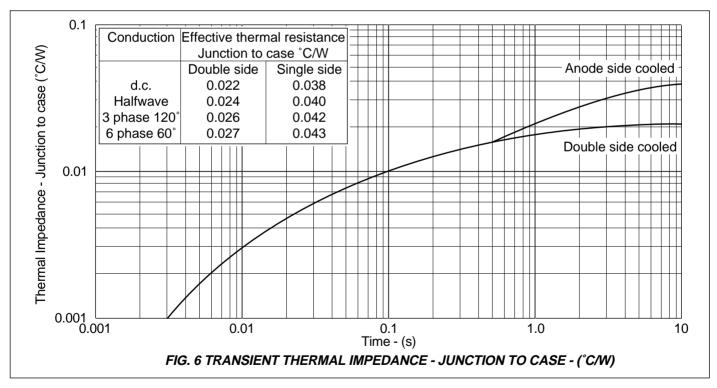
### CURVES





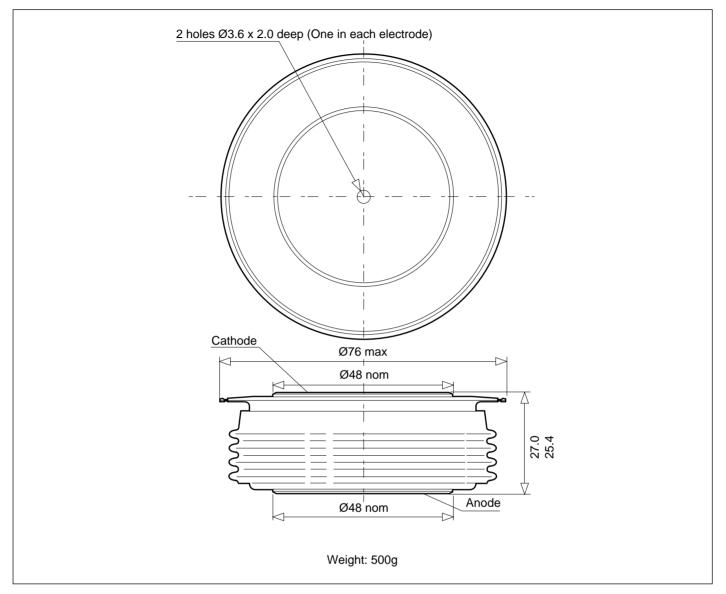






## PACKAGE DETAILS - F

For further package information, please contact your local Customer Service Centre. All dimensions in mm, unless stated otherwise. DO NOT SCALE.



DS2007SF



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